

**Vishay Siliconix** 

# P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)		
30	0.0057 at $V_{GS}$ = - 10 V	- 24		
	0.0095 at V <sub>GS</sub> = - 4.5 V	- 17		

# PowerPAK SO-8

Bottom View

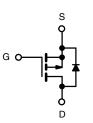
Ordering Information: Si7483ADP-T1-E3 (Lead (Pb)-free) Si7483ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)

### **FEATURES**

- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Power MOSFETS
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile
- 100 % R<sub>q</sub> tested

### APPLICATIONS

- Battery and Load Switching
  - Notebook Computers
  - Notebook Battery Packs



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T <sub>A</sub> = 25 °C, unles	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	- 30		V	
Gate-Source Voltage		V <sub>GS</sub>	± 20			
Continuous Drain Current (T - 150 °C)a	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 24	- 14	٨	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 19	- 11		
Pulsed Drain Current		I <sub>DM</sub>	- 60		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 4.5	- 1.6		
Maximum David Disainatiand	T <sub>A</sub> = 25 °C	P <sub>D</sub>	5.4	1.9	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		3.4	1.2		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) <sup>b,c</sup>		-	260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 s	R <sub>thJA</sub>	18	23	
Maximum Junction-to-Ambient*	Steady State		50	65	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.0	1.5	

Notes

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Pb-free RoHS COMPLIANT HALOGEN FREE

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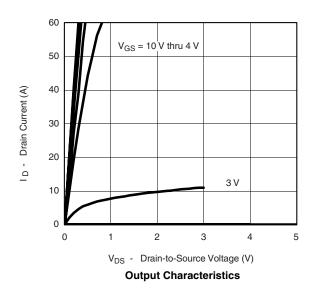
<b>SPECIFICATIONS</b> $T_J = 25 \circ 0$	C, unless o	otherwise noted				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static				•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0		- 3.0	V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zara Cata Valtaga Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V			- 1	
Zero Gate Voltage Drain Current		$V_{DS}$ = - 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 10	μA
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	- 30			А
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 24 A	0.0047 0.0057		0.0057	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 17 A			0.0095	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 24 A		70		S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 2.9 A, V <sub>GS</sub> = 0 V		- 0.73	- 1.1	V
Dynamic <sup>b</sup>						
Total Gate Charge	Qg			120	180	nC
Gate-Source Charge	Q <sub>gs</sub> Q <sub>gd</sub>	$V_{DS}$ = - 15 V, $V_{GS}$ = - 10 V, $I_{D}$ = - 24 A		18		
Gate-Drain Charge				33		l
Gate Resistance	Rg		1.6	3.2	4.8	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			22	35	
Rise Time	t <sub>r</sub>			33	50	ns
Turn-Off Delay Time	t <sub>d(off)</sub>			210	320	
Fall Time	t <sub>f</sub>			130	200	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.9 A, dl/dt = 100 A/μs		70	130	

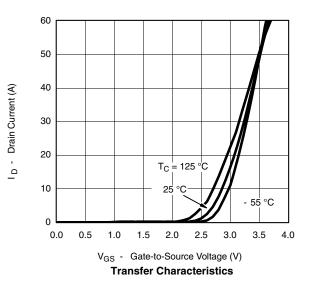
Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

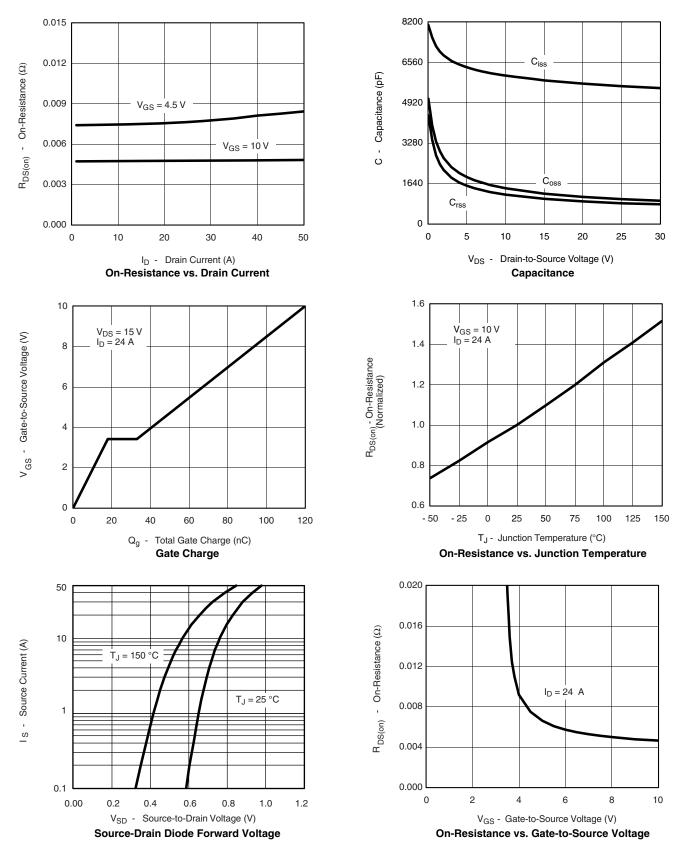






# Si7483ADP Vishay Siliconix

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



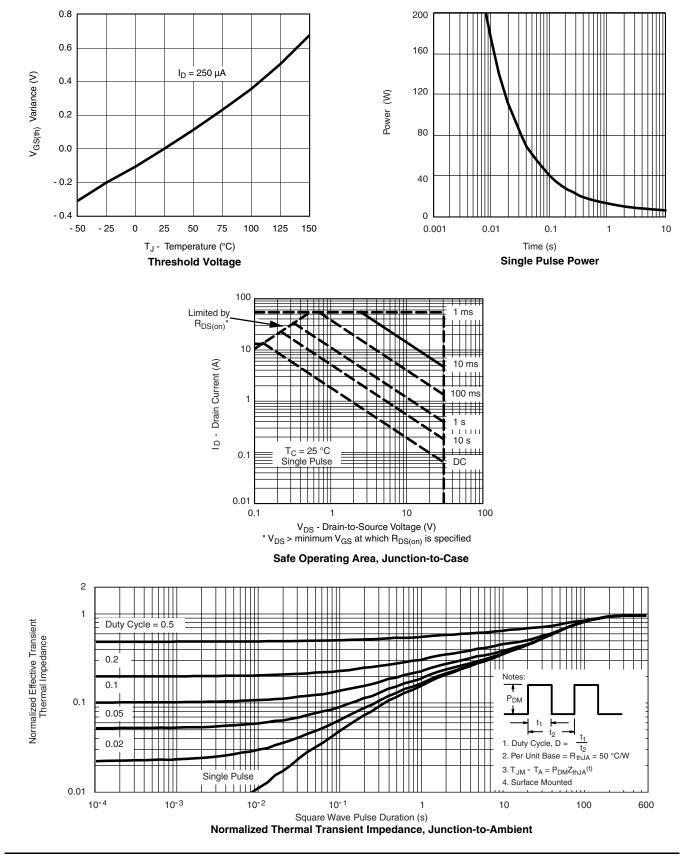
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# Si7483ADP

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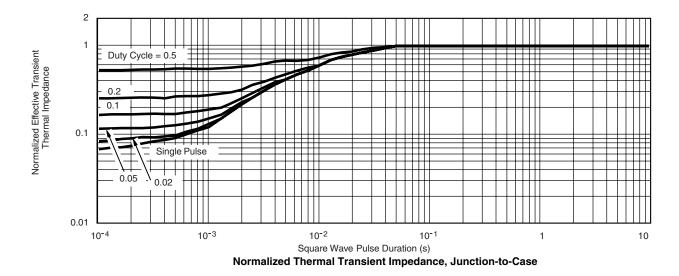
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Si7483ADP Vishay Siliconix

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